

SYNTHESIS AND CHARACTERIZATION
OF
NANOTUBES AND NANOPARTICLES
OF
ALUMINIUM NITRIDE

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Electron Temperature Calculation

Electron temperature calculation for arc (collision dominated) plasma was done by the following method. It was seen that the average electron temperature varied between 7,000 K to 12,000K depending on the arc current.

Formula Used :

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Where :

I_1 and I_2 are the intensities of the lines 1 & 2

g_1 and g_2 are the degeneracy of lines 1 & 2

A_1 and A_2 are the transition probability of levels 1 & 2

E_1 and E_2 are the excitation energy of levels 1 & 2

$$\begin{array}{lll} I_1 = 82 & I_2 = 36 & \lambda_1 = 327 \text{ nm} \\ g_1 = 3 & g_2 = 5 & \lambda_2 = 325.9 \text{ nm} \\ E_1 = 13.2213 & E_2 = 13.9287 & \\ A_1 = 0.21 \times 10^8/\text{s} & A_2 = 0.38 \times 10^8/\text{s} & \end{array}$$

$$\frac{82}{36} = \frac{3 \times 0.21 \times 10^8 \times 325.9}{5 \times 0.38 \times 10^8 \times 327.0} \exp\left[-\frac{13.22 - 13.92}{kT}\right]$$

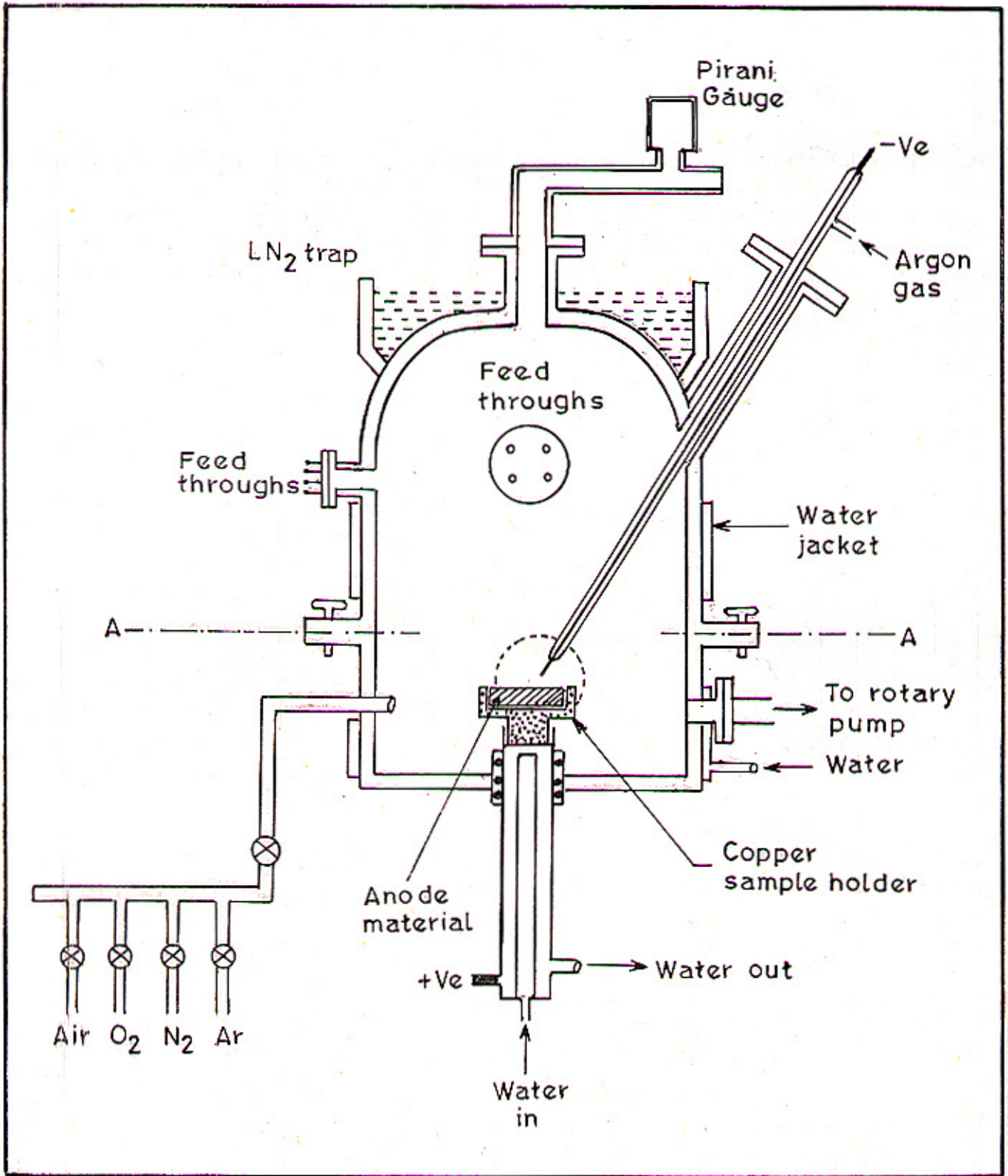
$$kT = \frac{0.7}{0.978} = 0.716 \text{ eV}; \quad \underline{T_e = 8294 \text{ K}}$$

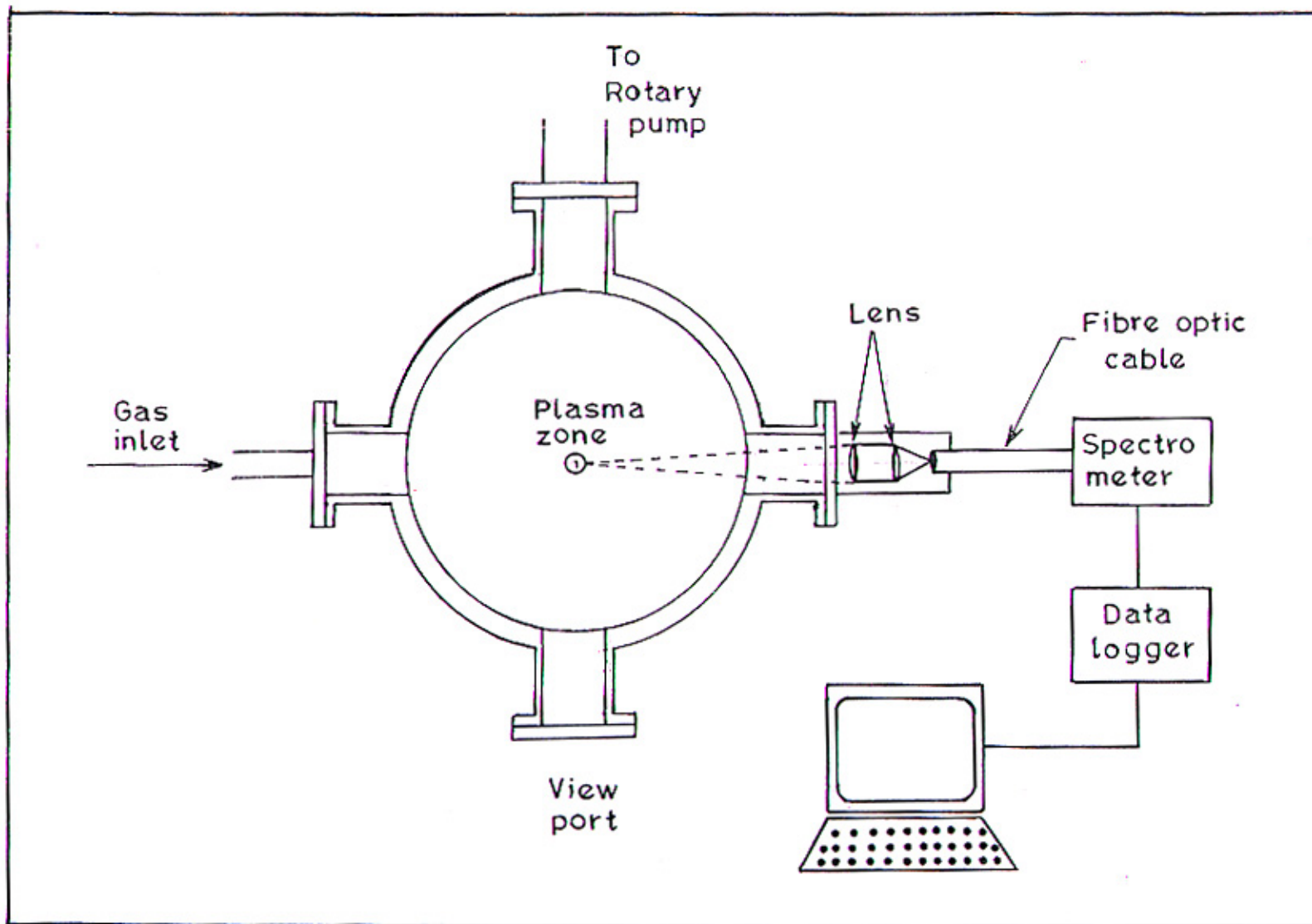
ADVANTAGES OF PLASMA SYNTHESIS

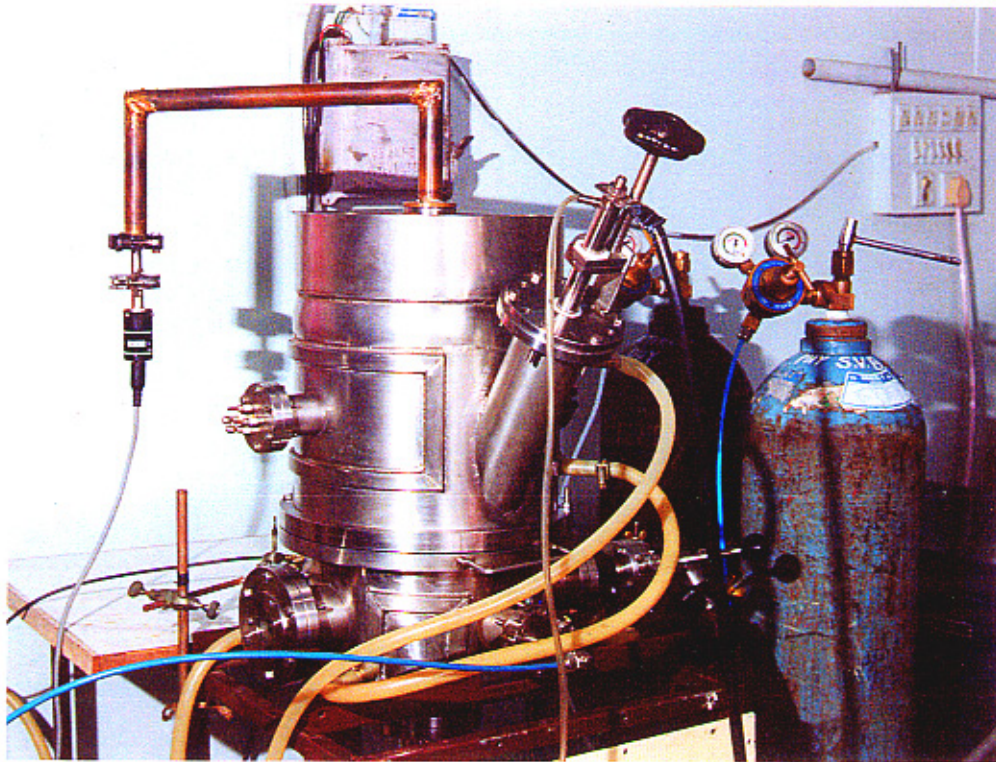
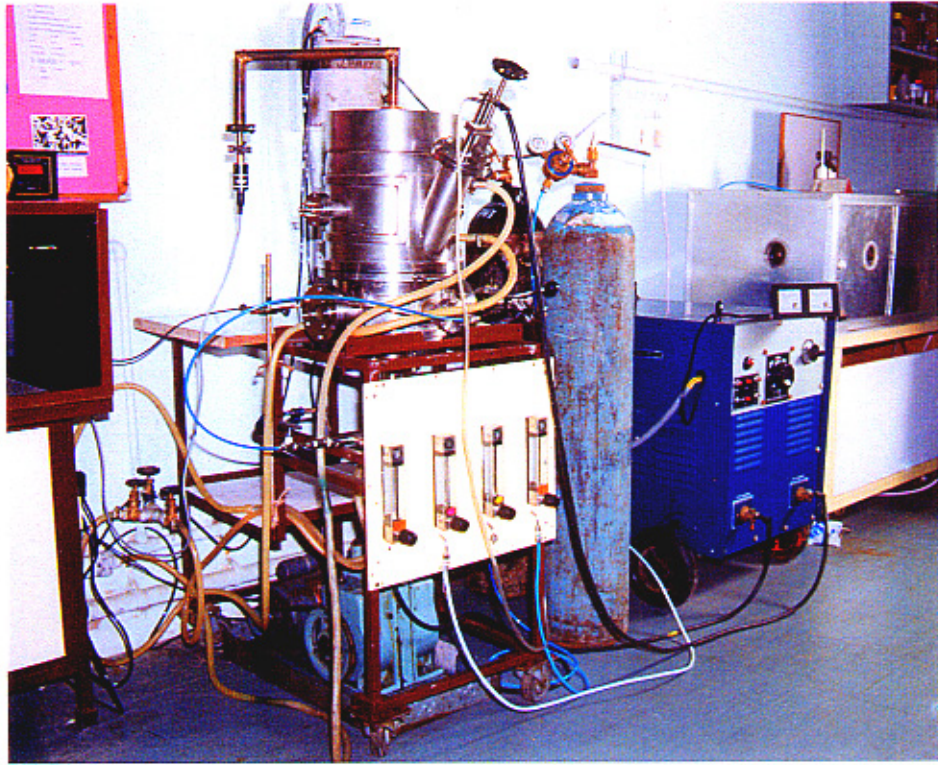
- High temperature reaction – Ceramics can also be synthesized
- This method also helps in the spectroscopic study of the reaction mechanism
- Wide range of materials can be synthesized without change in experimental set up.
- Crystalline phases are obtained
- High purity
- Simple to Use
- High vacuum not necessary

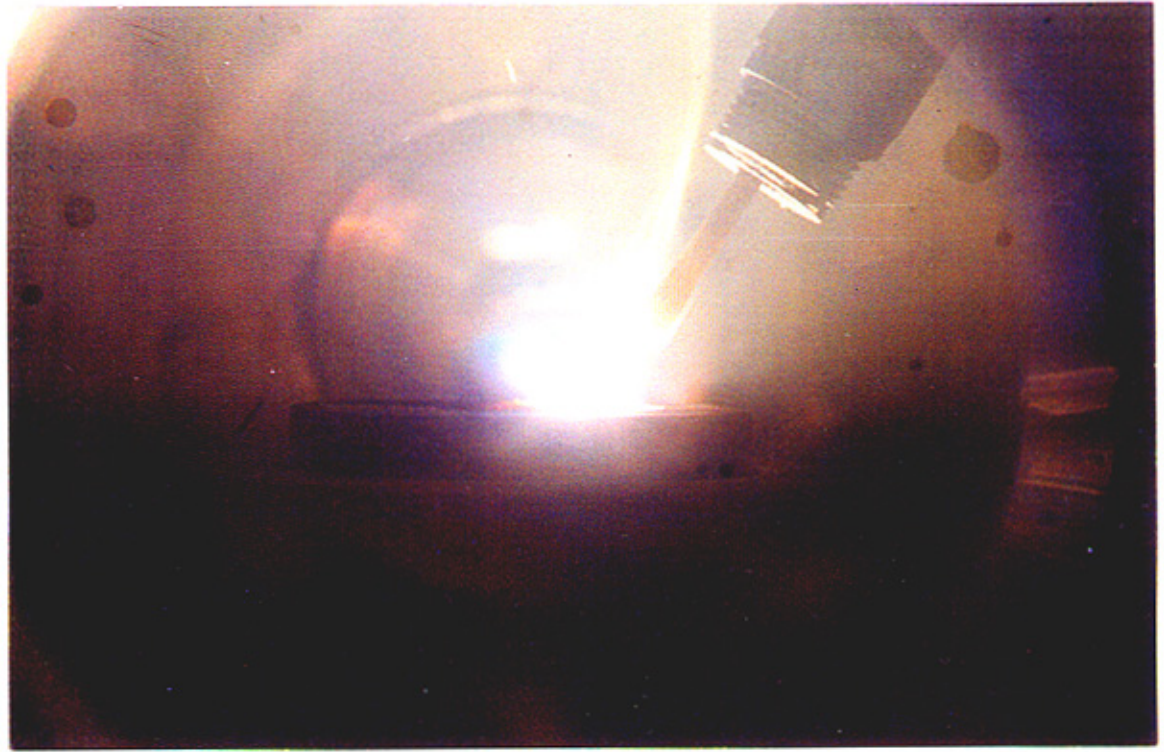
SYNTHESIS PARAMETERS

- ▼ Type of plasma : DC Transferred Arc Plasma
- ▼ Anode : Aluminium
- ▼ Cathode : Tungsten (2 mm dia)
- ▼ Arc Voltage : 12 – 20 V (OCV – 70 V)
- ▼ Arc Current : 50A, 100 A, 150 A
- ▼ Base Pressure : 10^{-3} Torr
- ▼ Operating Pressure : 500 – 600 Torr
- ▼ Chamber Volume : 0.02 m^3
- ▼ Reacting Gas : N_2 (Flow rate – 1.5 lit/min)
- ▼ Plasma Gas : Argon (0.5 lit/min)

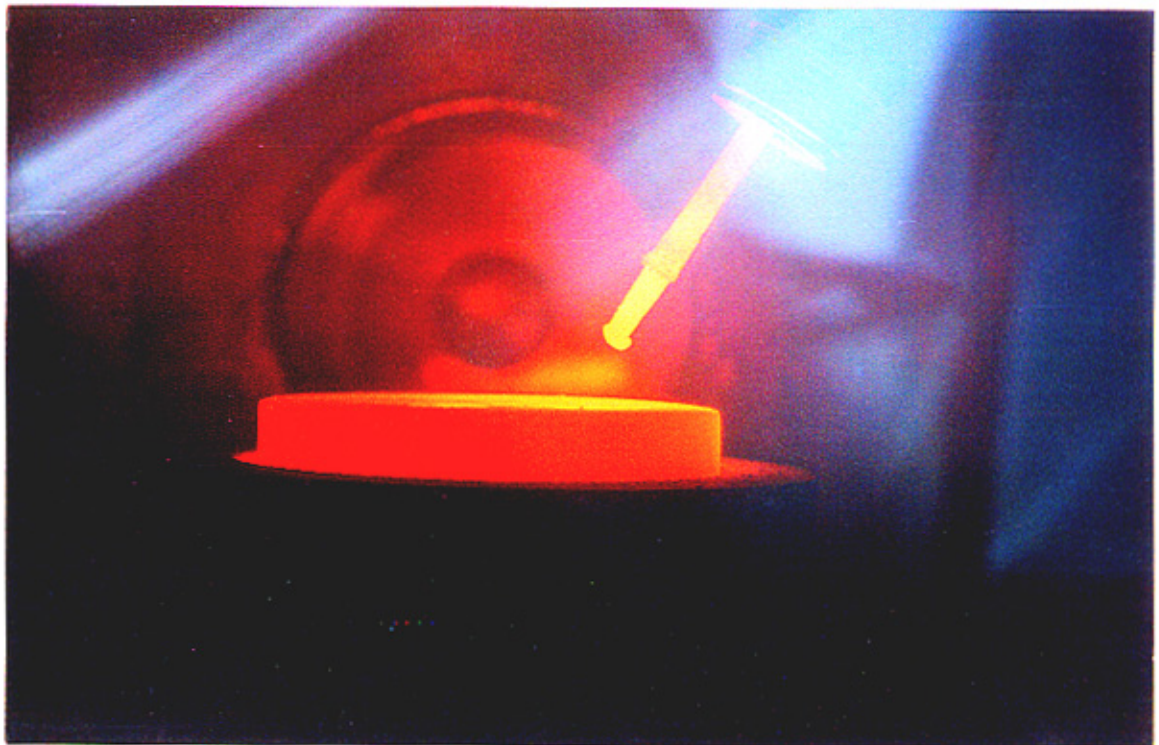








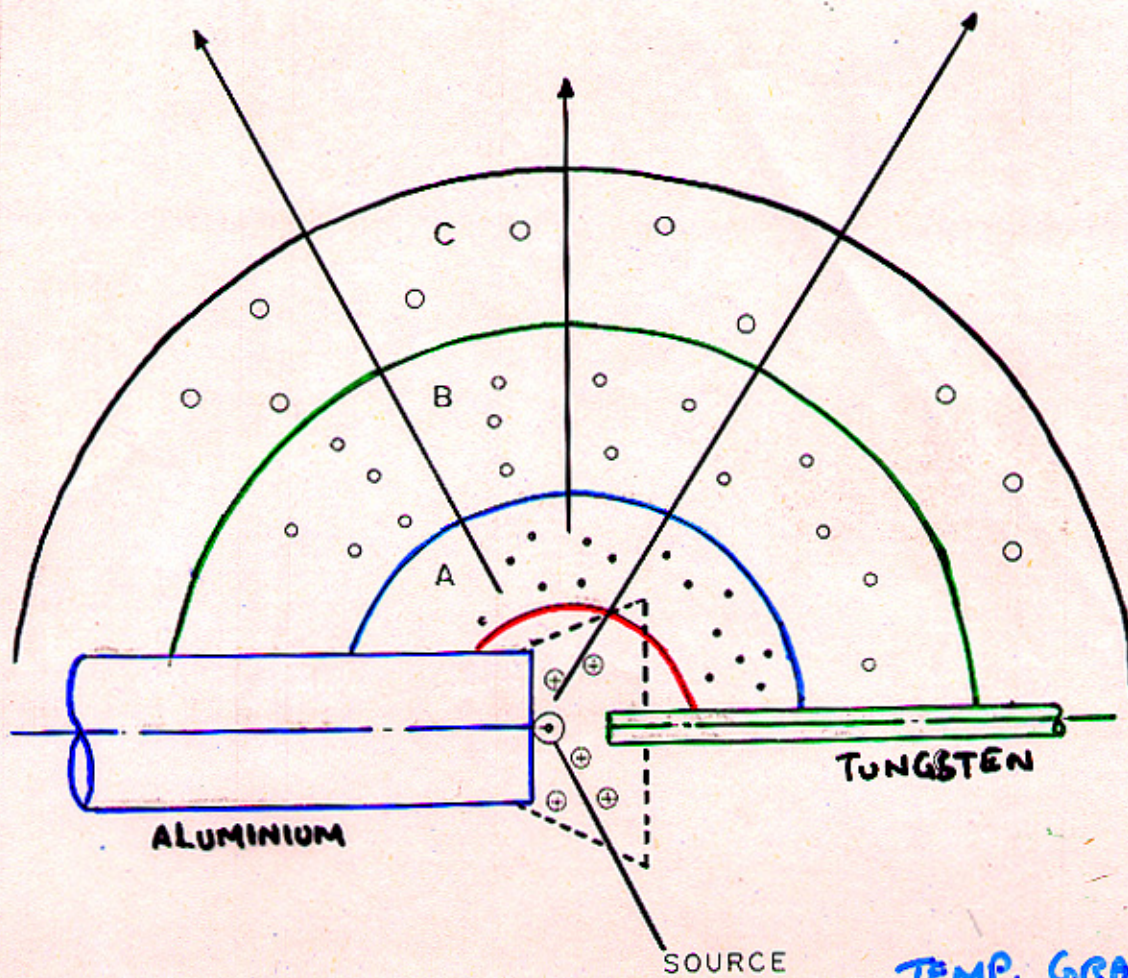
(a)



(b)

Fig. 5: Photograph showing the tungsten rod cathode and the graphite block anode (a) during arcing and (b) immediately after the arc is extinguished

⊙ : SOURCE , ⊕ : NUCLEATING SITES , ---- : PLASMA ZONE



TEMP. GRADIENT
 10^3 K/cm

NUCLEATION

- ▶ METAL ATOMS FROM THE SOURCE WILL RAPIDLY LOSE THEIR ENERGY
- ▶ METAL VAPOUR IS COOLED IN THE GAS
- ▶ COLLISION FREE PATH IS VERY SHORT

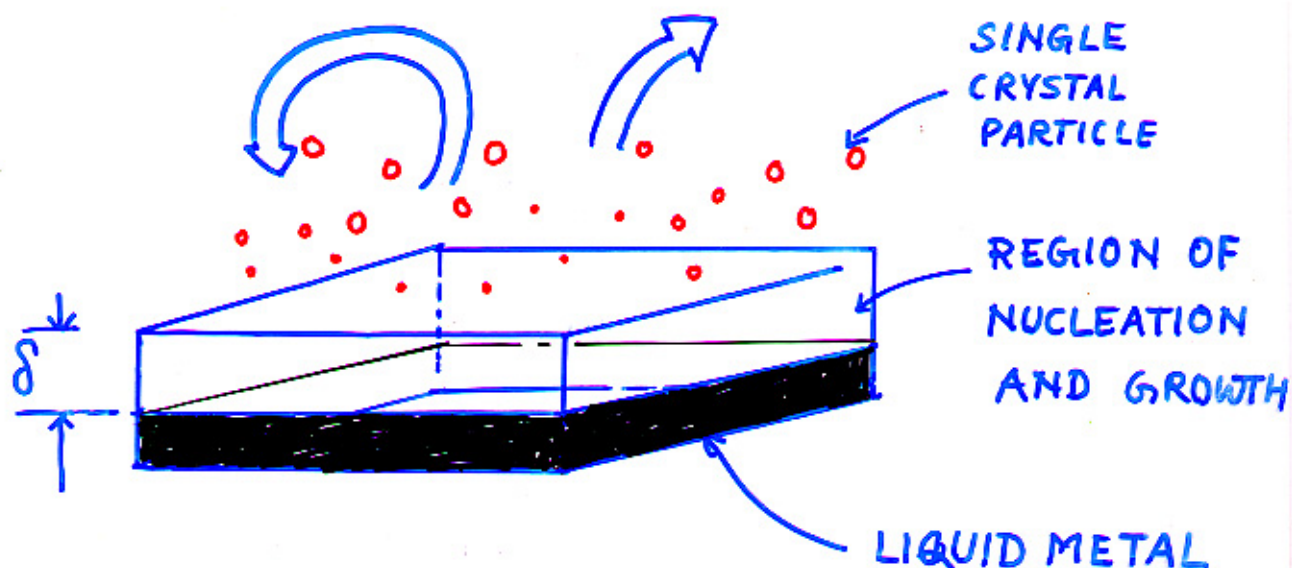
CRITICAL DIAMETER FOR EMBRYO

$$x_{crit} = 4 [\rho R T \ln (p_v / p_0)]^{-1}$$

ρ = density R = gas constant

p_v / p_0 = Supersaturation ratio.

- ▶ HOMOGENEOUS NUCLEATION



GAS PHASE SYNTHESIS

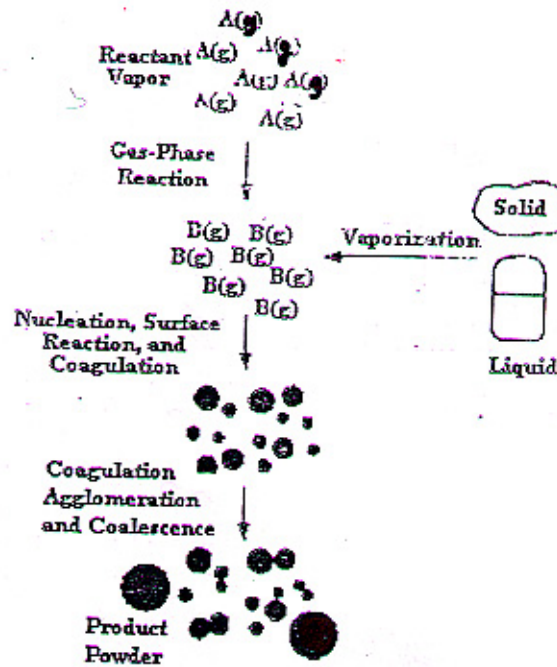


Fig. 2. Gas-to-particle conversion process.

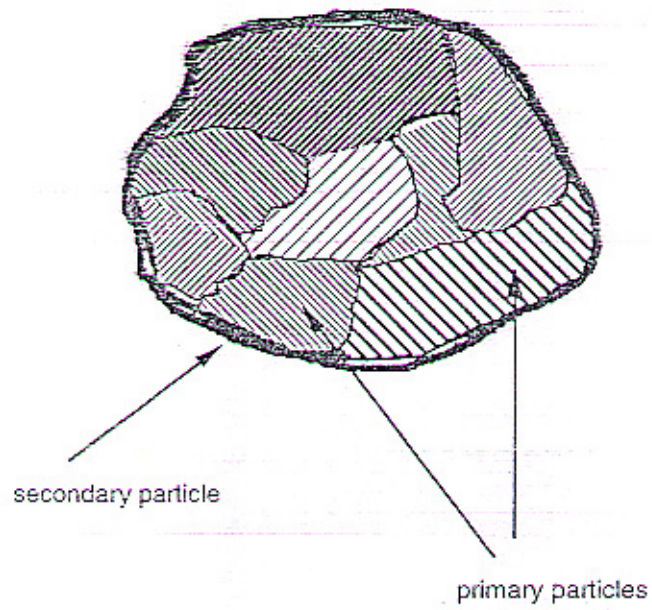


Figure 3.1. A schematic diagram showing the primary and secondary particles.

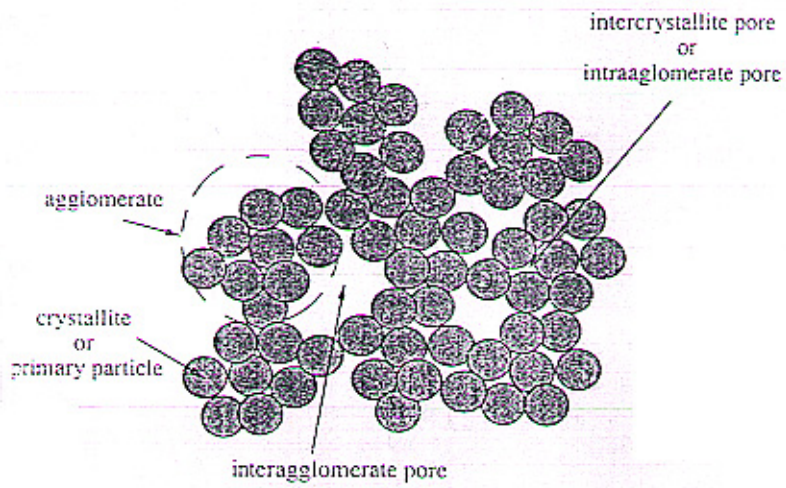
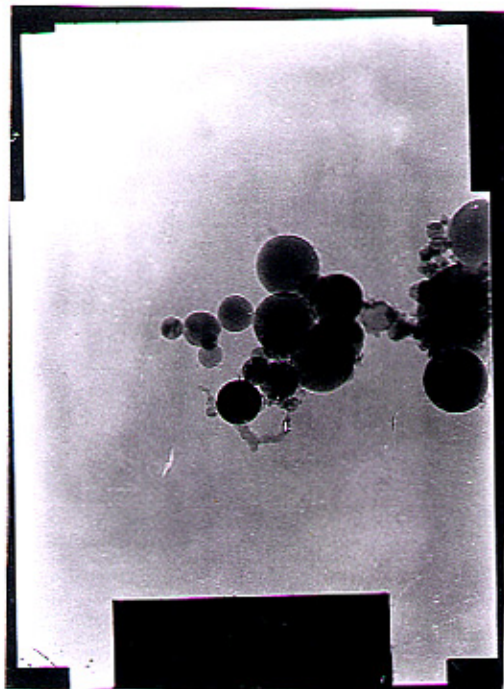


Figure 8.2. Schematic diagram of an agglomerated powder.

PROPERTIES OF ALN

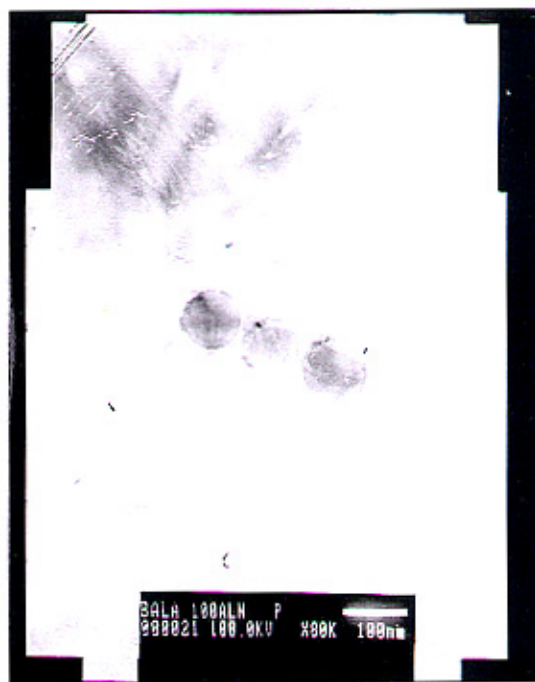
- * LARGE BANDGAP (~ 6.2 eV - BULK) SEMICONDUCTOR
- * HIGH THERMAL CONDUCTIVITY.
COEFFICIENT OF THERMAL EXPANSION (LOW)
MATCHES WITH THAT OF SILICON
- * POTENTIAL CANDIDATE FOR OPTO ELECTRONIC
AND ELECTRO ACOUSTIC DEVICES
- * PIEZOELECTRIC PROPERTY
- * CHEMICALLY STABLE
- * HEXAGONAL (STABLE) & CUBIC (METASTABLE)
PHASES

I = 50A
PARTICLE SIZE : 15-40 nm

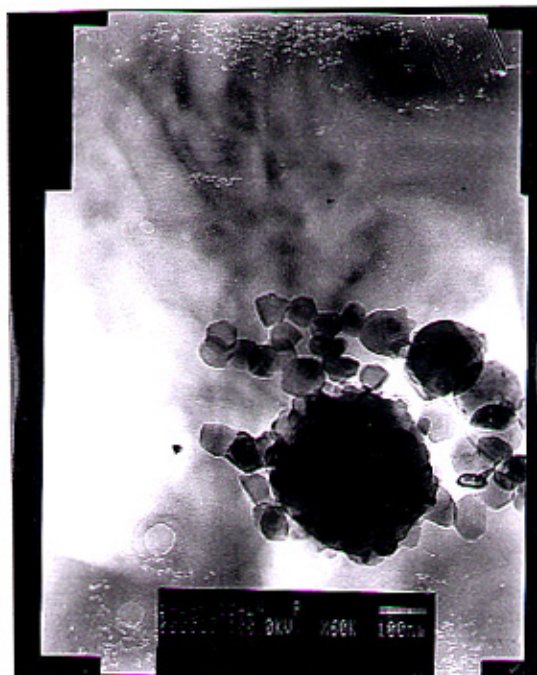


(a)

I = 100A
PARTICE SIZE : ~ 80nm



(b)



(c)

I = 150A
PARTICLE SIZE :
100- 200 nm

TEM micrographs of AlN nanoparticles synthesised at arc current of (a) 50 A (b) 100 A and (c) 150 A. For arc current of 50 A the particles are perfectly spherical in shape; for 100 A the particles are slightly distorted spherical shape and for 150 A the particles are hexagonal shaped.

Dia : $\sim 25-35$ nm
Length : $\sim 500-700$ nm



(a)

Dia : ~ 40 nm
length : ~ 600 nm

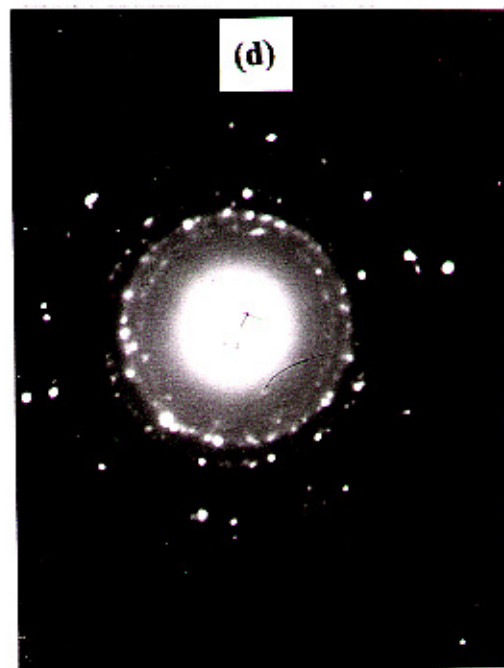
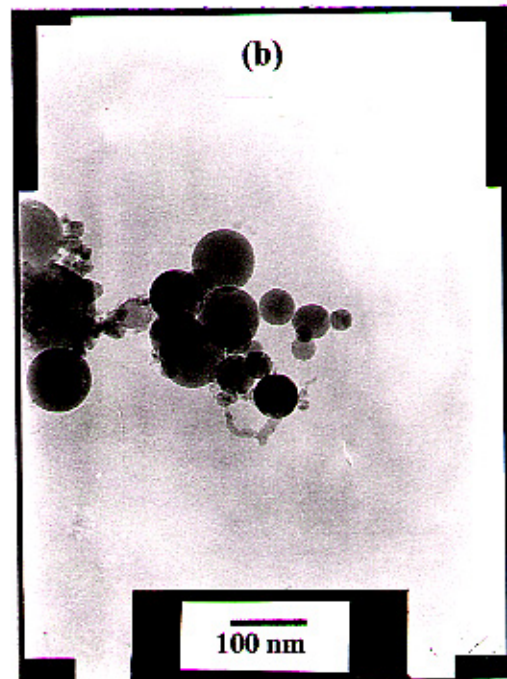


(b)



(c)

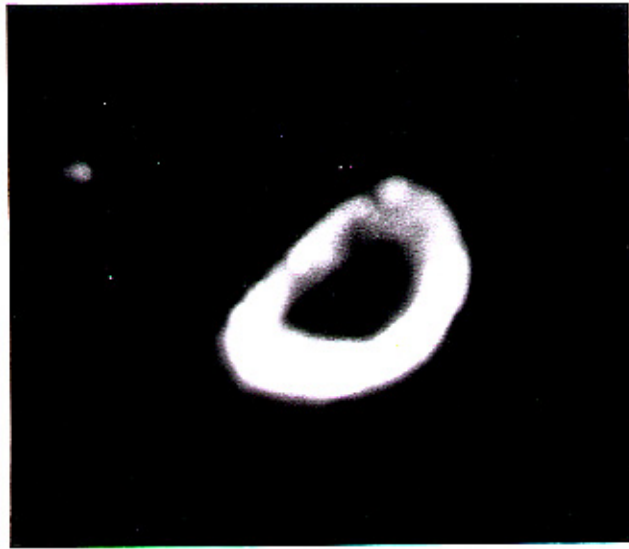
Fig. 10 : TEM micrographs of AlN nanotubes and nanoparticles synthesised at arc currents of (a) 50 A (b) 100 A and (c) 150 A. It is seen that for 50 A arc current the nanotube formation is large; for 100 A arc current the nanotube formation is much less and for 150 A there is nanotube formation.



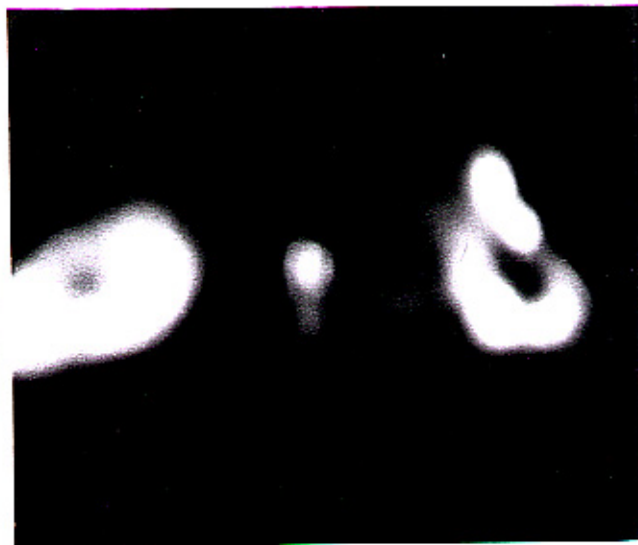
THE BIGGEST SIZE
NANOTUBE OBSERVED

TEM

SELECTED AREA
DIFFRACTION PATTERN



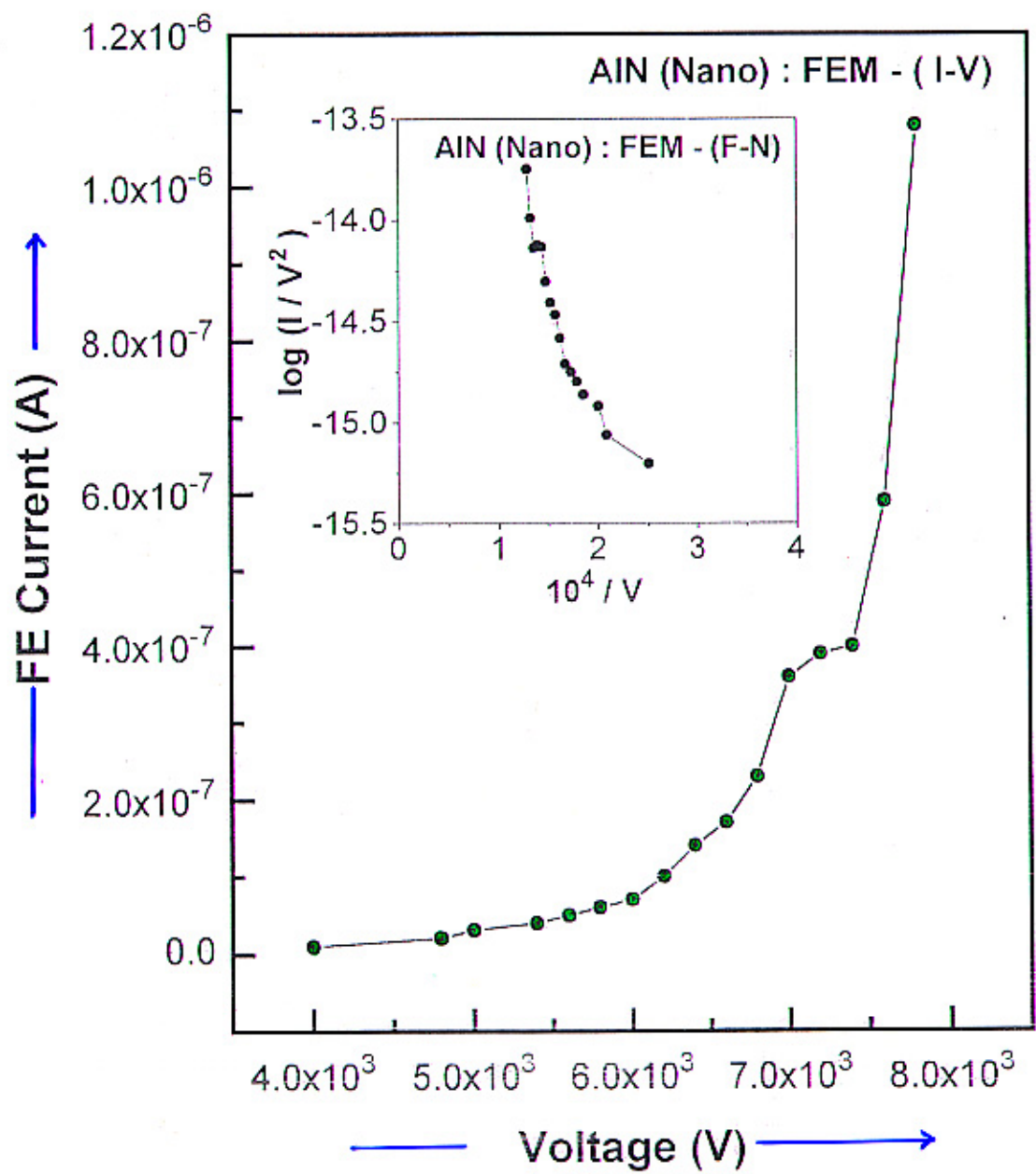
(a)



(b)

MAG : $\approx 10^6$
SIZE : O.D. = 35 nm
I.D. = ≈ 20 nm

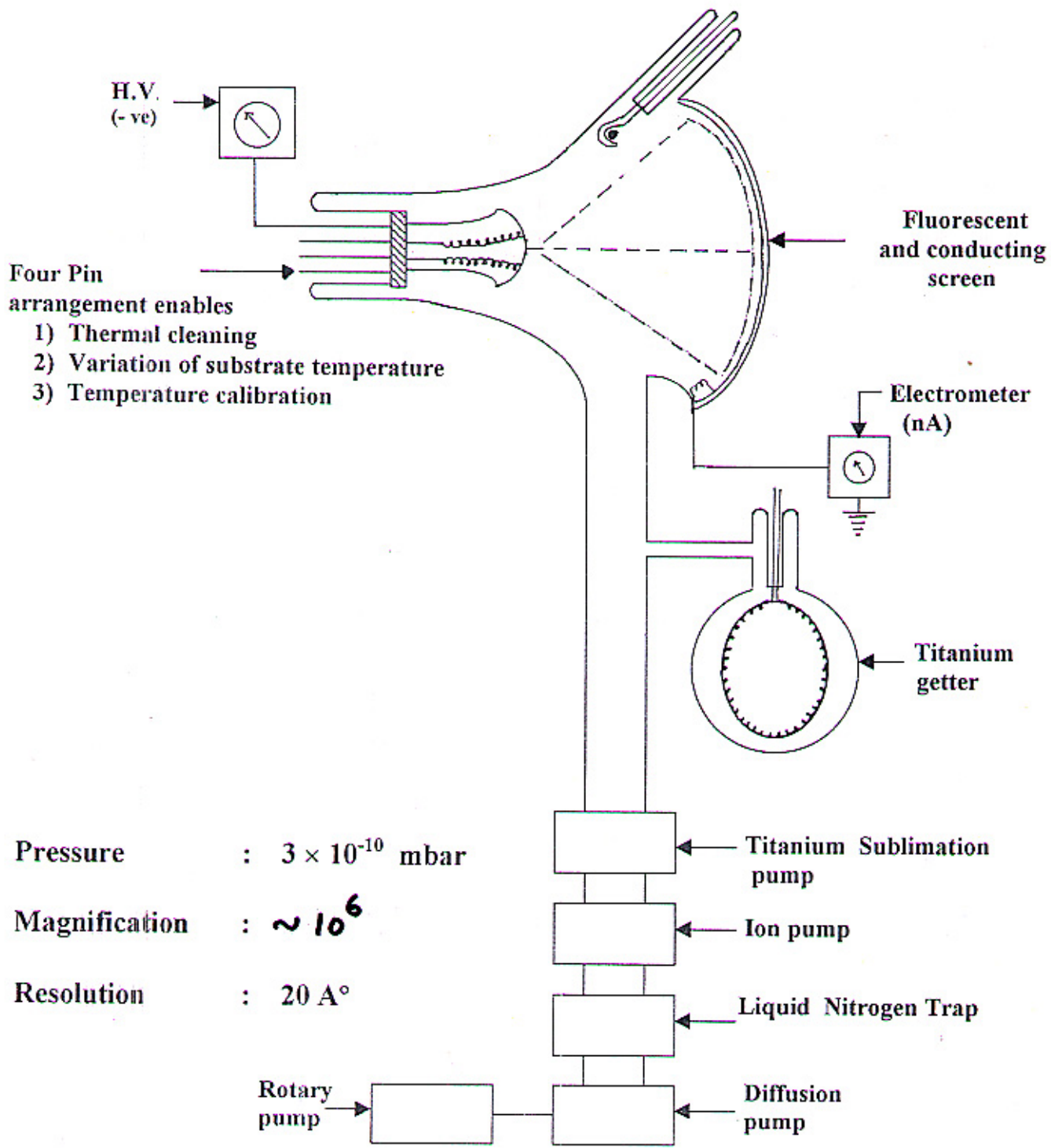
* Dynamically changing shape
* field 10^7 V/cm
* β (F.E.F) : 75,000



10 nA at 4 kV
 1 μA at 7.7 kV

F-N Plot non-linear
 ⇒ semi insulating nature

Experimental Setup of Field Emission Microscopy



Pressure : 3×10^{-10} mbar

Magnification : $\sim 10^6$

Resolution : 20 \AA

*AlN coated on W wire of 0.1 mm
Tip radius : 0.5 μm*

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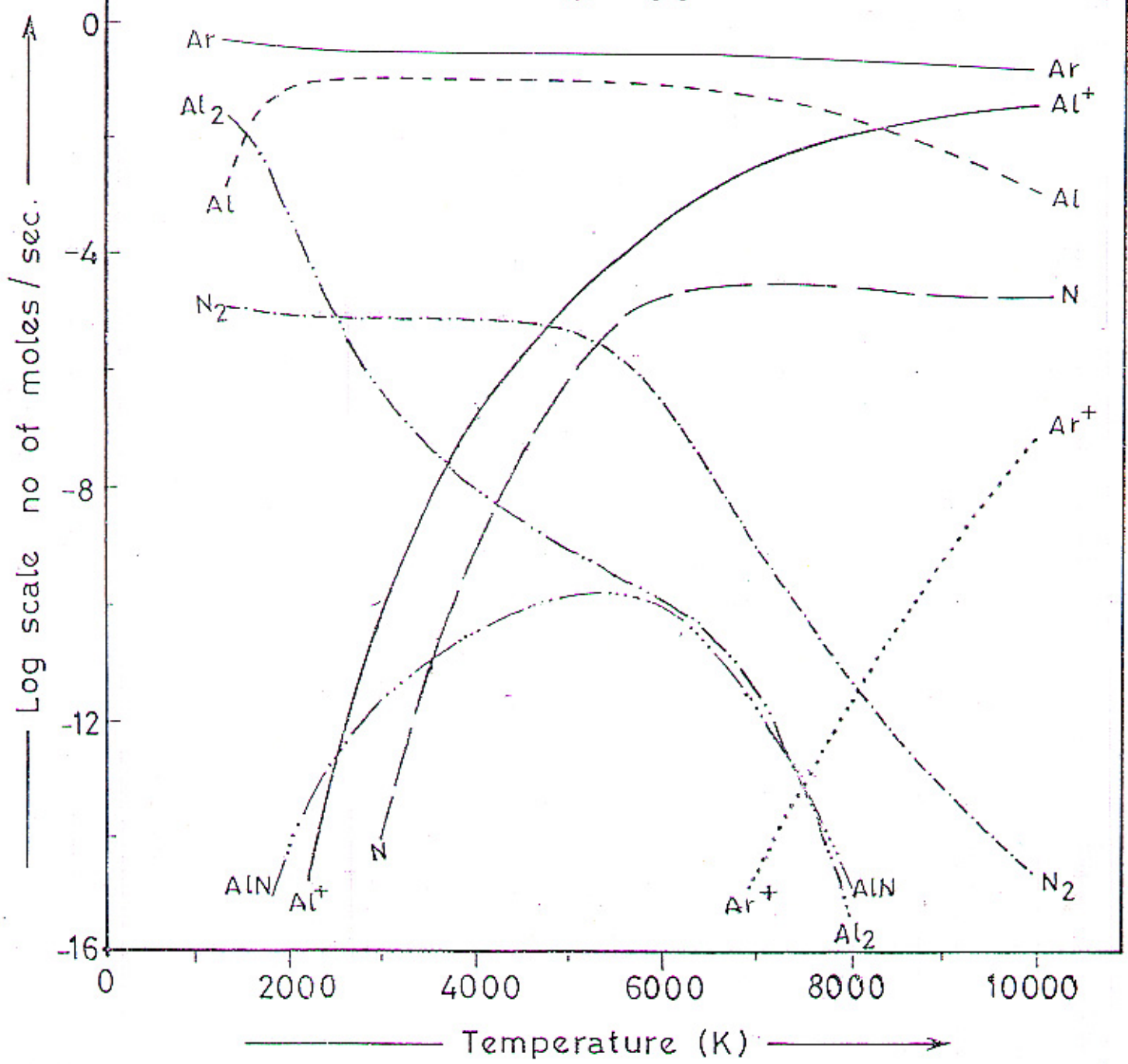
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THEORETICAL MODELING

A Fortran code was developed to estimate the concentration of various species that are expected to be present in the arc zone under a given set of temperature, pressure and input elements. This was done by **building a general purpose multi component equilibrium code**. This method is based on the **solution of the non-linear mass action equations coupled to the mass and charge conservation conditions**. **Newton Raphson** technique was used to solve the set of coupled non-linear equations in composition variables.

This programme can currently handle **35 gas and ionized** species formed from 4 elements and electron. The species were divided into basic components, which generated the rest of the other species through chemical reactions amongst themselves.

$P = 1.01 \text{ atm.}$ $Q_{\text{Al}} = 1.8889 \times 10^{-3}$ $Q_{\text{N}} = 5.9236 \times 10^{-5} \text{ moles/sec.}$
 $Q_{\text{Ar}} = 2.98 \times 10^{-3}$
 $Q_{e^-} = 0.0$



CONCLUSIONS

- NANO PARTICLES OF ALUMINIUM NITRIDE (Diameter ~ 30 nm) have been Synthesised.
- NANOTUBES (of length 500-700 nm and diameter 30-40 nm) of AlN has been Synthesised for the first time.
- It has been found Possible to Synthesise cubic (metastable) Phase of AlN by the non-equilibrium nature of plasma.

ACKNOWLEDGEMENT

SEMICONDUCTING AND INSULATING SOLIDS LABORATORY

Group Leader

Prof. Sudha V. Boraskar

Members

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|---|---|---|
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